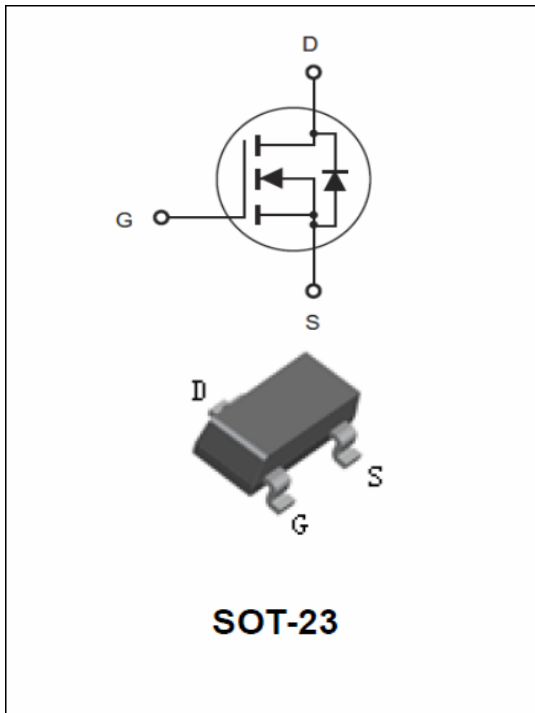


## N-Channel Enhancement Mode Field Effect Transistor



### Feature

- $V_{DS}=20V, I_D=4.3A$
- $R_{DS(ON)} < 27m\Omega @ V_{GS}=4.5V$
- $R_{DS(ON)} < 44m\Omega @ V_{GS}=2.5V$
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level1
- High density cell design for low  $R_{DS(ON)}$
- High Speed switching
- Rugged and reliable
- SOT-23 Package

### Application

- Battery protection
- Load switch
- Power management

### ■ Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-source Voltage	20	V
$V_{GS}$	Gate-source Voltage	$\pm 10$	V
$I_D$	Drain Current	4.3	A
$I_{DM}$	Pulsed Drain Current	17	A
$P_D$	Total Power Dissipation	1	W
$R_{thJA}$	Thermal Resistance From Junction To Ambient	125	°C/W
$T_J$	Operation Junction Temperature	-55~+150	°C
$T_{STG}$	Storage Temperature	-55~+150	°C

### ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL2302A	F2		3000	30000	120000	7" reel



# YJL2302A

## ■ Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$			1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{GS}= \pm 10V, V_{DS}=0V$			$\pm 100$	nA
Gate threshold voltage*	$V_{GS(th)}$	$V_{DS}= V_{GS}, I_D=250\mu A$	0.6	0.85	1.1	V
Drain-source on-resistance*	$R_{DS(on)}$	$V_{GS}= 4.5V, I_D=4.3A$		21	27	m $\Omega$
		$V_{GS}= 2.5V, I_D=4.0A$		29	44	
Forward Transconductance	$g_{FS}$	$V_{DS}= 5V, I_D=4.3A$	5			s
<b>Dynamic Characteristics **</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V, f=1MHz$		482		pF
Output Capacitance	$C_{oss}$			85		
Reverse Transfer Capacitance	$C_{rss}$			52		
<b>Switching Characteristics**</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD}=10V, V_{GS}=4.5V, RL=2.8\Omega, I_D=1A, R_{GEN}=6\Omega$		13		ns
Turn-on rise time	$t_r$			54		
Turn-off delay time	$t_{d(off)}$			18		
Turn-off Fall time	$t_f$			11		
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=4.3A, V_{GS}=4.5V$		4.2		nC
Gate-Source Charge	$Q_{gs}$			0.9		
Gate-Drain Charge	$Q_{gd}$			1.4		
<b>Source-Drain Diode characteristics</b>						
Drain-Source Diode Forward Current	$I_S$				4.3	A
Diode Forward voltage	$V_{SD}$	$V_{GS}=0V, I_S=4.3A$		0.8	1.2	V

Notes:

\*Pulse Test: Pulse Width $\leq$ 300 $\mu$ A, Duty Cycle $\leq$ 2%.

\*\*These parameters have no way to verify.

## ■ Characteristics (Typical)

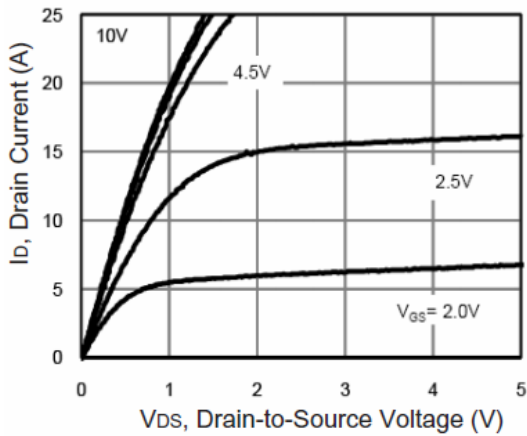


Figure 1. Output Characteristics

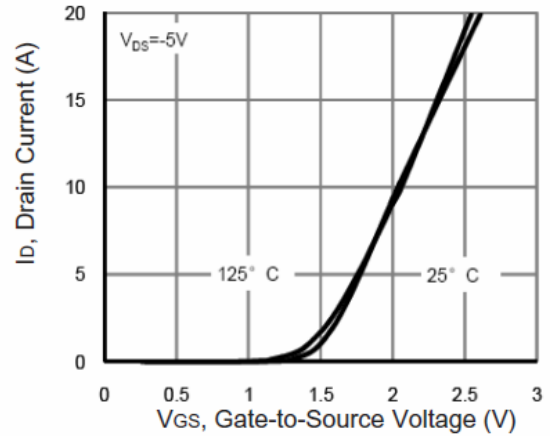


Figure 2. Transfer Characteristics

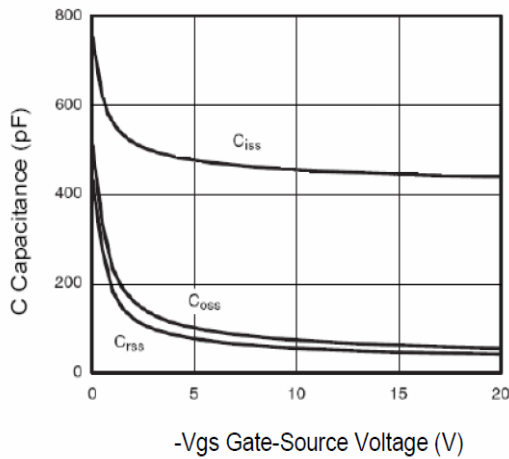


Figure 3. Capacitance

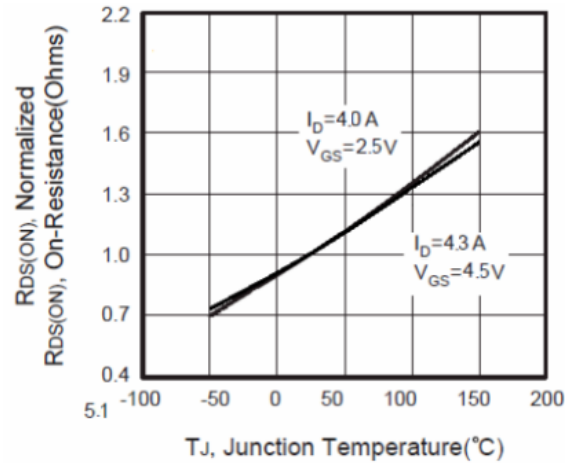


Figure 4. On-Resistance Variation with Temperature

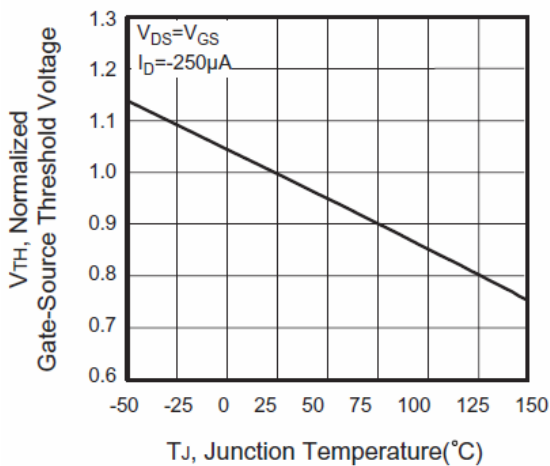


Figure 5. Gate Threshold Variation with Temperature

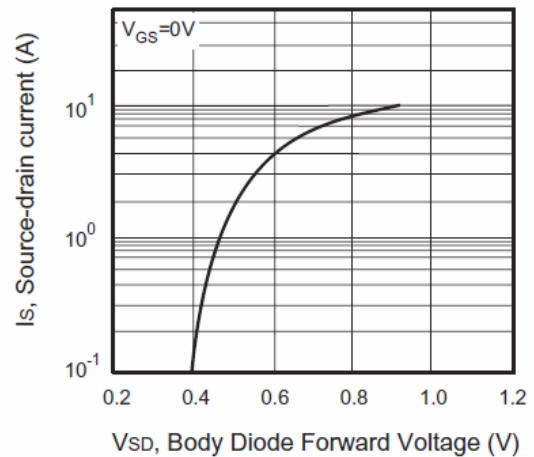
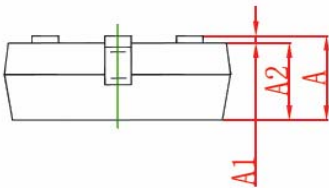
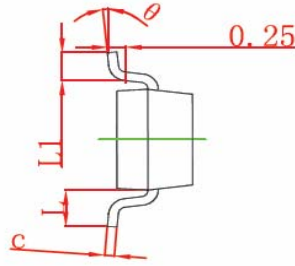
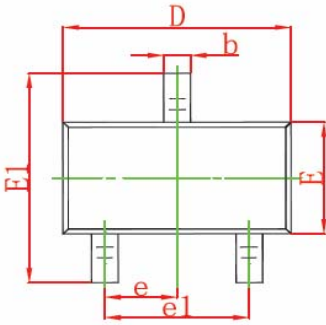


Figure 6. Body Diode Forward Voltage Variation with Source Current



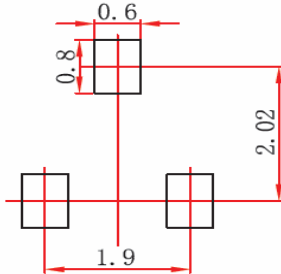
# YJL2302A

## ■ SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°		8°	

## ■ SOT-23 Suggested Pad Layout



Note:  
1. Controlling dimension: in millimeters.  
2. General tolerance:  $\pm 0.05\text{mm}$ .  
3. The pad layout is for reference purposes only.



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